

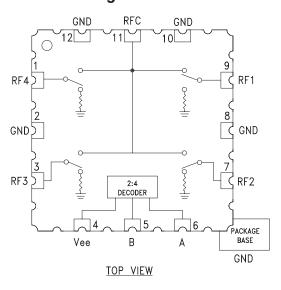


Typical Applications

This switch is suitable for DC - 12.0 GHz 50-Ohm Systems

- Telecom Infrastructure
- Military Radio, Radar & ECM
- Space Systems
- Test Instrumentation

Functional Diagram



Features

Broadband Performance: DC - 12 GHz

High Isolation: 42 dB@ 6 GHz

Low Insertion Loss: 1.8 dB@ 6 GHz

Integrated 2:4 TTL Decoder

Hermetic SMT Package, 25 mm²

Screening to MIL-PRF-38535 (Class B or S) Available

General Description

The HMC344LH5 is a broadband non-reflective GaAs MESFET SP4T switch in a hermetic SMT leadless package. Covering DC to 12 GHz, this switch offers high isolation and low insertion loss. This switch also includes an on board binary decoder circuit which reduces the required logic control lines to two. The switch operates using a negative control voltage of 0/-5V, and requires a fixed bias of -5V. Simple external level shifting circuitry allows this switch to be controlled with most TTL/CMOS positive logic families. The HMC344LH5 allows the use of surface mount manufacturing techniques and is suitable for high reliability military, industrial and space applications.

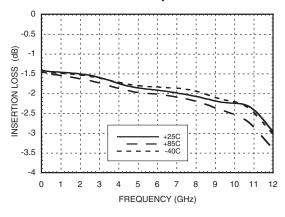
Electrical Specifications, $T_A = +25^{\circ}$ C, With Vee = -5V & 0/-5V Control, 50 Ohm System

Parameter		Frequency	Min.	Тур.	Max.	Units
Insertion Loss		DC - 2.0 GHz DC - 6.0 GHz DC - 8.0 GHz DC - 12.0 GHz		1.5 1.8 2.1 3.0	1.9 2.2 2.5 3.4	dB dB dB dB
Isolation		DC - 2.0 GHz DC - 4.0 GHz DC - 6.0 GHz DC - 8.0 GHz DC - 12.0 GHz	48 43 37 35 30	53 48 42 40 35		dB dB dB dB
Return Loss	"On State"	DC - 10.0 GHz DC - 12.0 GHz		17 12		dB dB
Return Loss	"Off State"	DC - 8.0 GHz DC - 12.0 GHz		16 10		dB dB
Input Power for 1 dB Compression		0.5 - 12.0 GHz	24	27		dBm
Input Third Order Intercept (Two-Tone Input Power = +7 dBm Each Tone)		0.5 - 4.0 GHz 4.0 - 8.0 GHz 8.0 - 12.0 GHz		50 47 44		dBm dBm dBm
Switching Characteristics tRISE, tFALL (10/90% RF) tON, tOFF (50% CTL to 10/90% RF)		DC - 12.0 GHz		35 75		ns ns

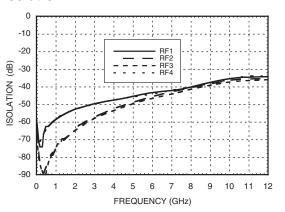




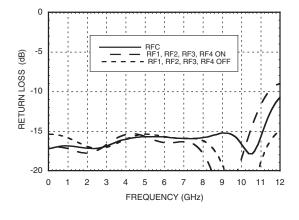
Insertion Loss vs. Temperature



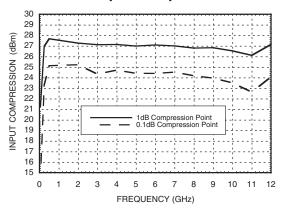
Isolation



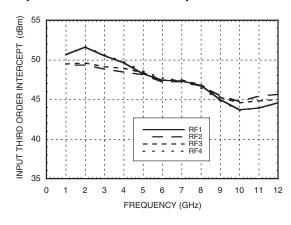
Return Loss



0.1 and 1 dB Input Compression Point



Input Third Order Intercept Point



Bias Voltage & Current

Vee Range = -5.0 Vdc ± 10%			
Vee (Vdc)	lee (Typ.) (mA)	lee (Max.) (mA)	
-5.0	3.0	6.0	

Control Voltages

State	Bias Condition
Low	-3V to 0 Vdc @ 40 uA Typical
High	-5 to -4.2 Vdc @ 5 uA Typical

^{*} Isolation is recorded above insertion loss & measured at output of switch.





Absolute Maximum Ratings

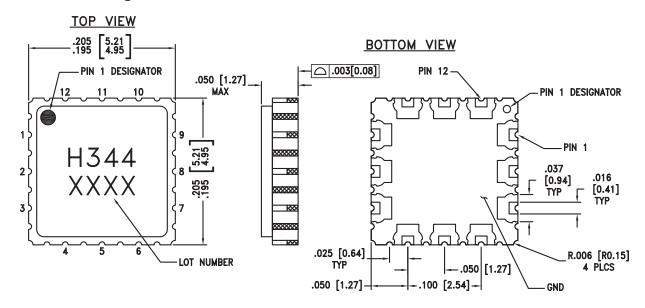
Bias Voltage Range (Vee)	-7.0 Vdc
Control Voltage Range (A & B)	Vee -0.5V to +1.0 Vdc
Channel Temperature	150 °C
Thermal Resistance (Insertion Loss Path)	157 °C/W
Continuous Pdiss (T= 85 °C) (derate 6.4 mW/°C above 85 °C)	0.42 W
Thermal Resistance (Terminated Path)	264 °C/W
Continuous Pdiss (T= 85 °C) (derate 3.8 mW/°C above 85 °C)	0.25 W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
Maximum Input Power	+28 dBm (0.5 - 12.0 GHz)
ESD Sensitivity (HBM)	Class 1A

Truth Table

Control Input		Signal Path State	
Α	В	RFC to:	
High	High	RF1	
Low	High	RF2	
High	Low	RF3	
Low	Low	RF4	



Outline Drawing



NOTES:

- PACKAGE BODY MATERIAL: CERAMIC & KOVAR
- 2. LEAD AND GROUND PADDLE PLATING: GOLD 40 80 MICROINCHES.
- 3. DIMENSIONS ARE IN INCHES [MILLIMETERS].
- 4. LEAD SPACING TOLERANCE IS NON-CUMULATIVE
- 5. PAD BURR LENGTH 0.15mm MAX. PAD BURR HEIGHT 0.25mm MAX.
- 6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.

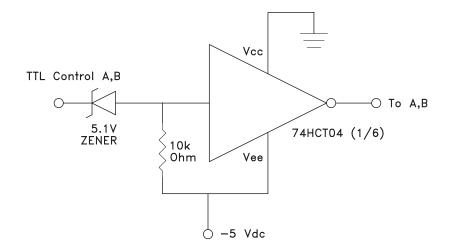




Pin Descriptions

Pin Number	Function	Description	Interface Schematic	
1, 3, 7, 9, 11	RF4, RF3, RF2, RF1, RFC	This pin is DC coupled and matched to 50 Ohm. Blocking capacitors are required if RF line potential is not equal to 0V.		
2, 8, 10, 12	GND	Package base must also be connected to PCB RF ground.	GND =	
4	Vee	Supply Voltage -5V ± 10%		
5	В	See truth table and control voltage table.	100K	
6	А	See truth table and control voltage table.		

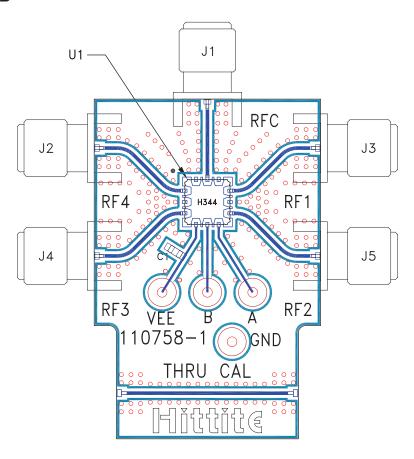
TTL Interface Circuit







Evaluation PCB



List of Materials for Evaluation PCB 110760 [1]

Item	Description	
J1 - J5	PCB Mount SMA RF Connector	
J6 - J9	DC Pin	
C1	10k pF Capacitor, 0603 Pkg.	
U1	HMC344LH5 SP4T Switch	
PCB [2]	110758 Evaluation PCB	

^[1] Reference this number when ordering complete evaluation PCB

The circuit board used in the final application should be generated with proper RF circuit design techniques. Signal lines at the RF port should have 50 ohm impedance and the package ground leads and package base should be connected directly to the ground plane similar to that shown above. The evaluation circuit board shown above is available from Hittite Microwave Corporation upon request.

^[2] Circuit Board Material: Rogers 4350



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SWITCHES - SM



ROHS V

GaAs MMIC SP4T NON-REFLECTIVE SWITCH, DC - 12 GHz

Notes: